TOSHIBA Field Effect Transistor Silicon P Channel MOS Type (U-MOSVI)

TPC6113

Lithium Ion Battery Applications Power Management Switch Applications

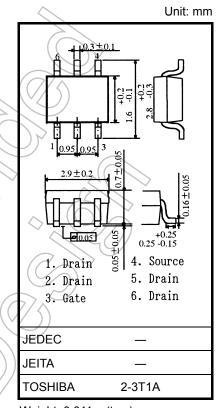
- Small footprint due to small and thin package
- Low drain-source ON-resistance: R_{DS} (ON) = 38 m Ω (typ.)

$$(V_{GS} = -4.5V)$$

- Low leakage current: $I_{DSS} = -10 \ \mu A \ (max) \ (V_{DS} = -20 \ V)$
- Enhancement mode: $V_{th} = -0.5$ to -1.2 V
- $(V_{DS} = -10 \text{ V}, \text{ I}_{D} = -0.2 \text{ mA})$

Absolute Maximum Ratings (Ta = 25°C)

Characteristics		Symbol	Rating	Unit		
Drain-source voltage		V _{DSS}	-20	V		
Drain-gate voltage ($R_{GS} = 20 \text{ k}\Omega$)		V _{DGR}	-20	V		
Gate-source voltage		V _{GSS}	±12	> v		
Drain current	DC	(Note 1)	I _D	_5	Α	
	Pulse	(Note 1)	I _{DP}	-20	A	
Drain power dissipatio	on	(t = 5 s) (Note 2a)	PD	2.2	W	
Drain power dissipatio	on	(t = 5 s) (Note 2b)	PD	0.7	W	//
Single pulse avalanche energy (Note 3)			EAS	1.6	mJ	
Avalanche current		HAR	-2.5	A		
Channel temperature		Tch	150	°C		
Storage temperature range			T _{stg}	-55 to 150	℃	



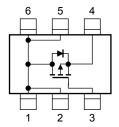
Weight: 0.011 g (typ.)

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated/failure rate, etc).

Thermal Characteristics

Characteristics	Symbol	Max	Unit
Thermal resistance, channel to ambient (t = 5 s) (Note 2a)	R _{th (ch-a)}	56.8	°C/W
Thermal resistance, channel to ambient (t = 5 s) (Note 2b)	R _{th (ch-a)}	178.5	°C/W

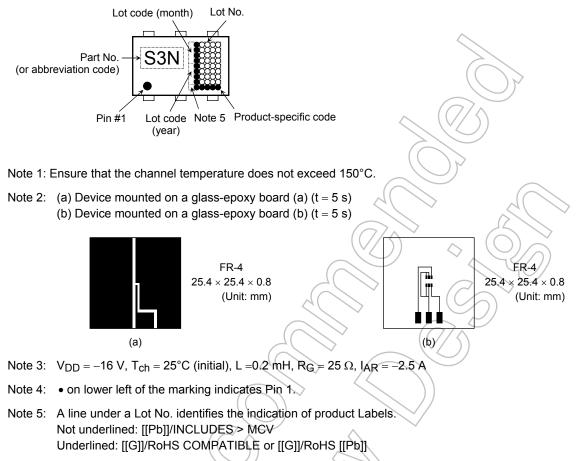
Circuit Configuration



Note: (Note 1), (Note 2), (Note 3) : See other pages.

This transistor is an electrostatic-sensitive device. Please handle with caution.

Marking (Note 4)



Please contact your TOSHIBA sales representative for details as to environmental matters such as the RoHS compatibility of Product. The RoHS is the Directive 2011/65/EU of the European Parliament and of the Council of 8 June 2011 on the restriction of the use of certain hazardous substances in electrical and electronic equipment.

Electrical Characteristics (Ta = 25°C)

Characteristics		Symbol	Test Condition	Min	Тур.	Max	Unit	
Gate leakage cur	rent	I _{GSS}	$V_{GS} = \pm 12 \text{ V}, \text{ V}_{DS} = 0 \text{ V}$			±100	nA	
Drain cut-off curr	ent	I _{DSS}	$V_{DS} = -20 \text{ V}, \text{ V}_{GS} = 0 \text{ V}$	_	_	-10	μA	
Drain-source breakdown voltage		V (BR) DSS	$I_D = -10$ mA, $V_{GS} = 0$ V	-20			V	
		V (BR) DSX	$I_D = -10$ mA, $V_{GS} = 8$ V (Note 6)	-10 mA, V _{GS} = 8 V (Note 6) -12		_	v	
Gate threshold ve	oltage	V _{th}	$V_{DS} = -10 \text{ V}, \text{ I}_{D} = -0.2 \text{ mA}$	-0.5)/	-1.2	V	
Drain-source ON-resistance		R _{DS (ON)}	$V_{GS} = -2.5 \text{ V}, \text{ I}_{D} = -2.5 \text{ A}$		56	85	m 0	
		R _{DS (ON)}	$V_{GS} = -4.5 \text{ V}, \text{ I}_{D} = -2.5 \text{ A}$	A	38	55	mΩ	
Input capacitance		C _{iss}			690	_		
Reverse transfer capacitance		C _{rss}	$V_{DS} = -10 \text{ V}, \text{ V}_{GS} = 0 \text{ V}, \text{ f} = 1 \text{ MHz}$	_	93	_	pF	
Output capacitance		C _{oss}			117	_		
Switching time	Rise time	tr	$V_{GS} = 2.5 \text{ A}$ -5 V 0 V -5 V 0 V 0	- (6	× ×	• ns	
	Turn-on time	t _{on}			13) —		
	Fall time	t _f		7	25	_		
	Turn-off time	t _{off}	$V_{DD} \approx -10 V$ Duty $\leq 1\%$, $t_W = 10 \ \mu s$	P	81	_		
Total gate charge (gate-source plus gate-drain)		Qg	$V_{DD} \approx -16 \text{ V}, \text{ V}_{GS} = -5 \text{ V},$	2 –	10			
Gate-source charge 1		Q _{gs1}	$I_D = -5 A$		1.3	_	nC	
Gate-drain ("miller") charge		Q _{gd}			2.8			

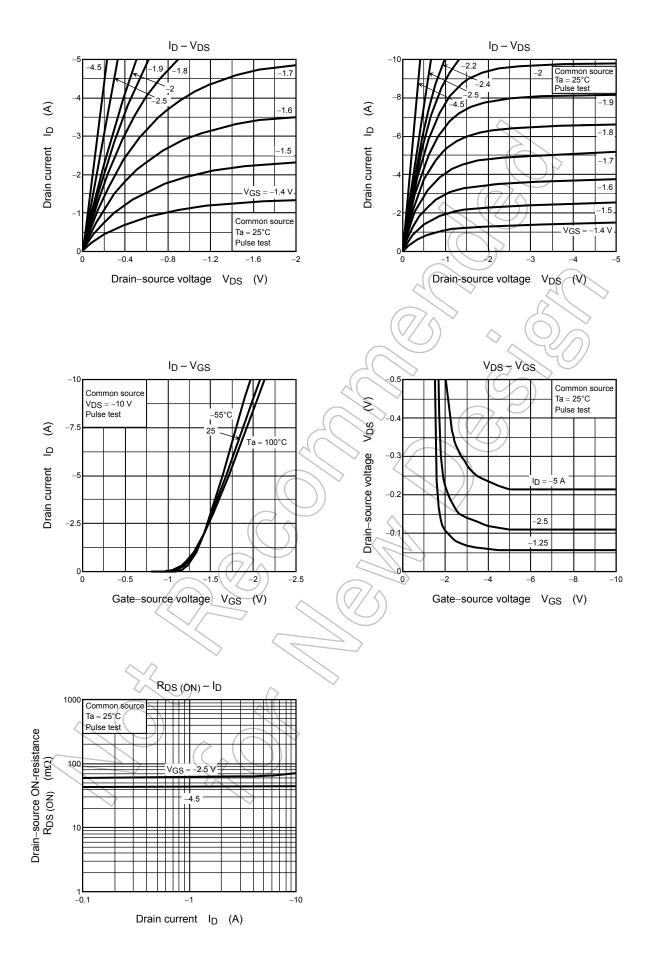
Source-Drain Ratings and Characteristics (Ta = 25°C)

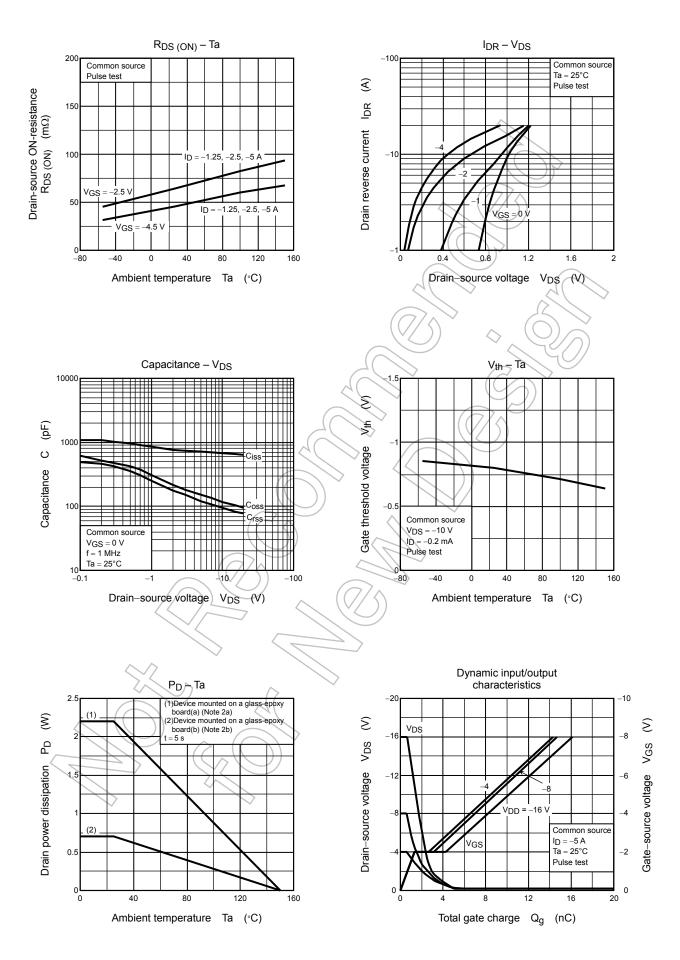
Charac	teristics	Symbol	Test Condition	Min	Тур.	Max	Unit
Drain reverse current	Pulse (Note 1)	IDRP		_	_	-20	А
Forward voltage	(diode)	V _{DSF}	$I_{\text{DR}} = -5 \text{ A}, V_{\text{GS}} = 0 \text{ V}$	_		1.2	V

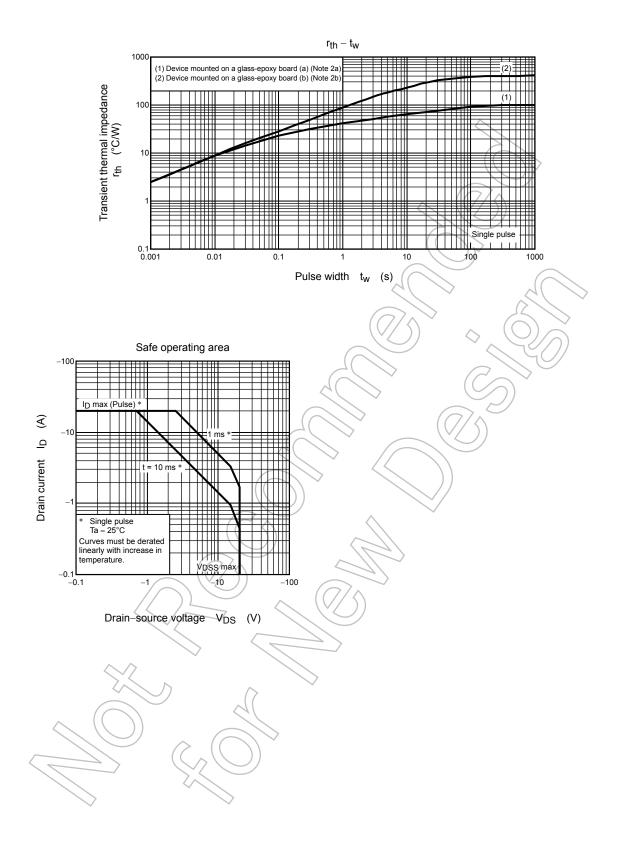
Note 6: VDSX mode (the application of a plus voltage between gate and source) may cause decrease in maximum rating of drain-source voltage.



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